Hitachi Ion Sputter MC1000



# Hitachi Ion Sputter

Specimen damage has been minimized through adoption of the magnetron type electrode.



### Specifications

### **Optional Accessories**

Item		Description
Discharge	Туре	Diode discharge magnetron type
		(electric field perpendicular to magnetic field)
	Electrode form	Opposed parallel disk (magnet embedded)
	Voltage	0.4 kV DC max. (variable through phase control)
	Current	40 mA DC max.
Coating rate (max.) *1*2		Pt target (ention) 15 nm (min
<conditions></conditions>		
Pressure:7 Pa		Pt-Pd target (option) 20 nm / min
Discharge current: 40 mA		Au target (option) 35 nm / min
Distance between target and specimen surface:30 mm		Au-Pd target (option) 25 nm / min
Specimen	Max. diameter	Ф60 mm
	Max. height	20 mm
Rotary pump		135 / 162 I / min (50 / 60 Hz)
Target <sup>*2</sup>		Pt, Pt-Pd (8:2), Au, Au-Pd (6:4)
Deven even har even in even to		Single phase, AC 100 V (±10 %) 15 A, (50 / 60 Hz),
Power supply requirements		3-Pin plug code (3 m)
Dimension	Width	450 mm
	Depth	391 mm
	Height	390 mm
Waight		Main unit: Approx.25 kg
weight		Rotary pump: Approx.28 kg



\*1: Coating rate is reference only. \*2: Target is not included in the main body. Please choose from the options.(Pt, Pt-Pd, Au, Au-Pd)

### **Optional Accessories**

Item	Description	
Layer Thickness Measurement &	Layer Thickness Measurement setting range: 1.0 to 30.0 nm	
cooling control Unit <sup>-3</sup>	Cooling temperature control range: Room temperature to (room temperature -25) ℃	
Evaporation unit	Evaporation material C (use of lead for Mechanical pencil)	
Large chamber*4	Max.diameter:Ф150 mm Max.height:20 mm	
Auto-transformer	Corresponded Voltage: 115, 200, 208, 220, 230, 240 V.	
	CE is not confirmed.	
** It should be ordered with main body simultaneously. It cannot be mounted to the large chamber		

\*4: It should be ordered with main body simultaneously.

### Installation Requirement / Items to be prepared by customer

Item	Description
Room temperature	15 to 30 ℃
Humidity	45 to 85 % or less
Power supply <sup>-₅</sup>	AC100 V (±10 %), 50/60 Hz, 1.25 kVA
Grounding	100 Ω or less
Argon gas cylinder	Pure gas (99.99 % or more)
Pressure regulator	Secondary pressure regulation range 0.03 to 0.05 Mpa
Argon gas connecting pipe <sup>*6</sup>	1/4-inch SUS pipe, Length within 2 m
Argon gas joint	1/4-inch Swagelok type pipe
Oximeter <sup>*7</sup>	18 % or more oxygen concentration capability
Recommend table	550 mm (W) $\times$ 550 mm (D) $\times$ 700 mm (H) or more,
	Withstand load : 30 kg or more

\*5: MC1000 is equipped with a power cord with 3-pin plug or with M6 crimp contact terminal.

\*6: Fiping and pressure regulator have to be prepared locally.
\*7: Ar gas is suffocative, please prepare ventilation system in the installation room. Please follow any applicable law or regulations for your safety.

NOTICE: For correct operation, follow the instruction manual when using the instrument.

Specifications in this catalog are subject to change with or without notice, as Hitachi High-Technologies Corporation continues to develop the latest technologies and products for our customers.

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